300MHz to 7GHz RF Power Detector with Buffered Output in SC70 Package

FEATURES

- **Temperature Compensated Internal Schottky Diode RF Detector**
- **Wide Input Frequency Range: 300MHz to 7GHz**
- **Wide Input Power Range: –32dBm to 12dBm**
- **Buffered Detector Output**
- **Wide V_{CC} Range of 2.7V to 6V**
- Low Operating Current: 550µA
- Low Shutdown Current: <2µA
- SC70 Package

APPLICATIONS

- 802.11a, 802.11b, 802.11g, 802.15
- Multimode Mobile Phone Products
- Optical Data Links
- Wireless Data Modems
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

DESCRIPTION

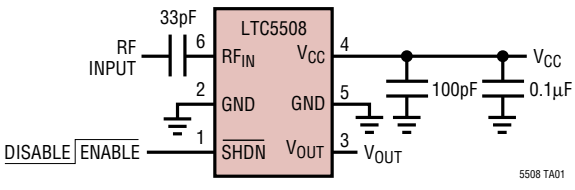
The LTC®5508 is an RF power detector for RF applications operating in the 300MHz to 7GHz range. A temperature compensated Schottky diode peak detector and buffer amplifier are combined in a small SC70 package. The supply voltage range is optimized for operation from a single lithium-ion cell or 3xNiMH.

The RF input voltage is peak detected using an on-chip Schottky diode. The detected voltage is buffered and supplied to the V_{OUT} pin. A power saving shutdown mode reduces supply current to less than 2µA.

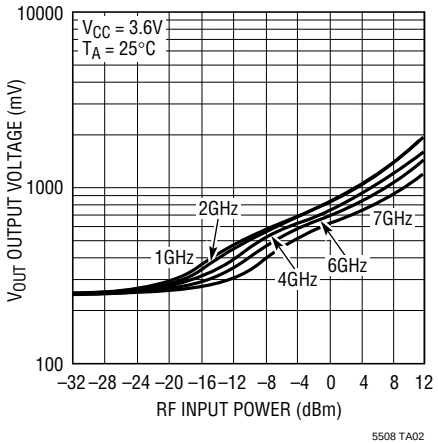
The LTC5508 operates with input power levels from –32dBm to 12dBm.

TYPICAL APPLICATION

300MHz to 7GHz RF Power Detector



Output Voltage vs RF Input Power

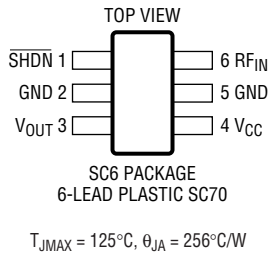


ABSOLUTE MAXIMUM RATINGS

(Note 1)

V_{CC}, V_{OUT} to GND ..... –0.3V to 6.5V
$\overline{RF_{IN}}$ Voltage ..... (V_{CC} ± 1.3V) to 7V
$\overline{SHDN}$ Voltage to GND ..... –0.3V to (V_{CC} + 0.3V)
I_{VOUT} 5mA
Operating Temperature Range (Note 2) .. – 40°C to 85°C
Maximum Junction Temperature ..... 125°C
Storage Temperature Range ..... – 65°C to 150°C
Lead Temperature (Soldering, 10 sec)..... 300°C

PACKAGE/ORDER INFORMATION



SC6 PACKAGE
6-LEAD PLASTIC SC70

T_{JMAX} = 125°C, θ_{JA} = 256°C/W

ORDER PART NUMBER
LTC5508ESC6
SC6 PART MARKING
LAAD

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{CC} = 3.6V, $\overline{SHDN}$ = V_{CC} = HI, $\overline{SHDN}$ = 0V = LO, RF Input Signal is Off, unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{CC} Operating Voltage		●	2.7		6	V
I_{VCC} Shutdown Current	$\overline{SHDN}$ = LO	●			2	µA
I_{VCC} Operating Current	$\overline{SHDN}$ = HI, I_{VOUT} = 0mA	●		0.55	0.85	mA
V_{OUT} V_{OL} (No RF Input)	R_{LOAD} = 2k, $\overline{SHDN}$ = HI, Enabled $\overline{SHDN}$ = LOW, Disabled		150	250 1	400	mV mV
V_{OUT} Output Current	V_{OUT} = 1.75V, V_{CC} = 2.7V, ΔV_{OUT} = 10mV	●	1	2		mA
V_{OUT} Enable Time	$\overline{SHDN}$ = HI, C_{LOAD} = 33pF, R_{LOAD} = 2k	●		8	20	µs
V_{OUT} Bandwidth	C_{LOAD} = 33pF, R_{LOAD} = 2k (Note 4)			2		MHz
V_{OUT} Load Capacitance	(Note 6)	●			33	pF
V_{OUT} Slew Rate	V_{RFIN} = 2V Step, C_{LOAD} = 33pF, R_{LOAD} = 2k (Note 3)			5		V/µs
V_{OUT} Noise	V_{CC} = 3V, Noise BW = 1.5MHz, 50Ω RF Input Termination			2		mV_{P-P}
$\overline{SHDN}$ Voltage, Chip Disabled	V_{CC} = 2.7V to 6V	●			0.35	V
$\overline{SHDN}$ Voltage, Chip Enabled	V_{CC} = 2.7V to 6V	●	1.4			V
$\overline{SHDN}$ Input Current	$\overline{SHDN}$ = 3.6V	●		24	40	µA
RF_{IN} Input Frequency Range				300 to 7000		MHz
RF_{IN} Input Power Range	RF Frequency = 300MHz to 7GHz (Note 5, 6) V_{CC} = 2.7V to 6V			–32 to 12		dBm
RF_{IN} AC Input Resistance	F = 1000MHz, Pin = –25dBm			150		Ω
RF_{IN} Input Shunt Capacitance	F = 1000MHz, Pin = –25dBm			0.6		pF

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: The rise time at V_{OUT} is measured between 0.5V and 1.5V.

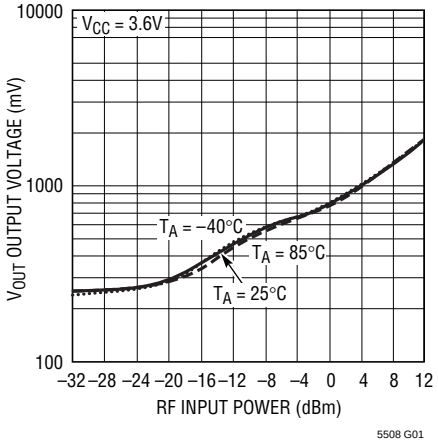
Note 4: Bandwidth is calculated using the 10% to 90% rise time equation: BW = 0.35/rise time.

Note 5: RF performance is tested at 1800MHz

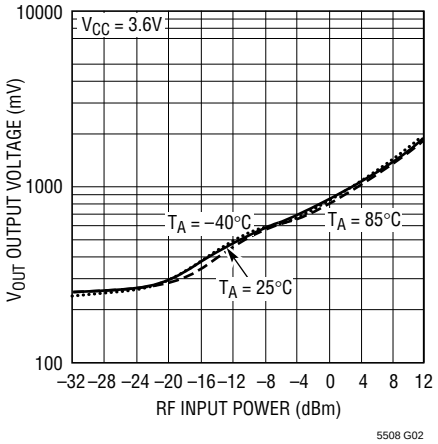
Note 6: Guaranteed by design.

TYPICAL PERFORMANCE CHARACTERISTICS

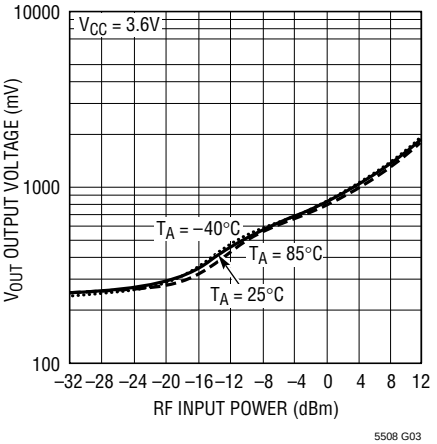
Typical Detector Characteristics, 300MHz



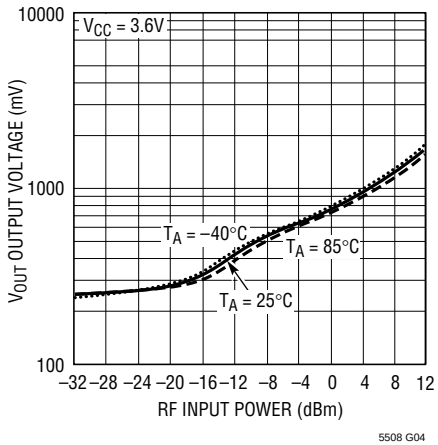
Typical Detector Characteristics, 1000MHz



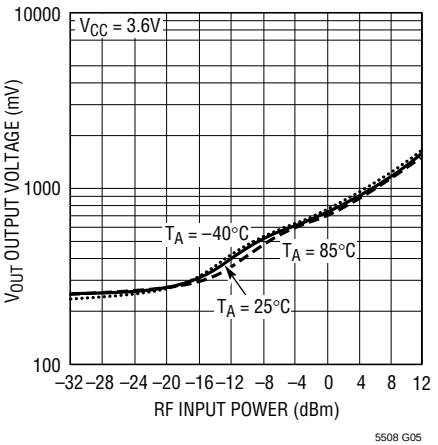
Typical Detector Characteristics, 2000MHz



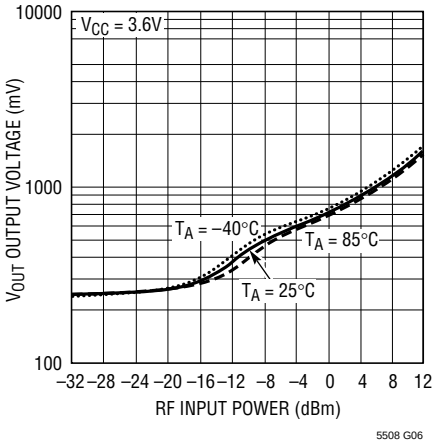
Typical Detector Characteristics, 3000MHz



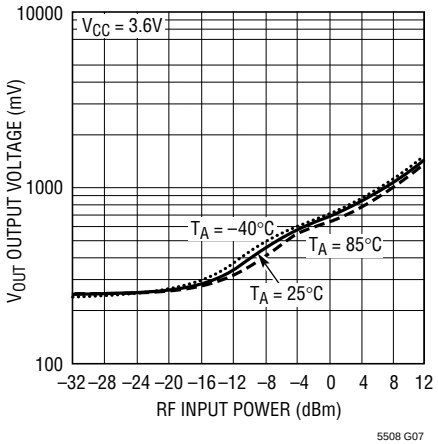
Typical Detector Characteristics, 4000MHz



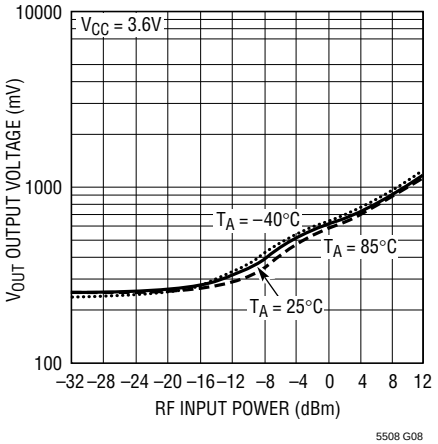
Typical Detector Characteristics, 5000MHz



Typical Detector Characteristics, 6000MHz

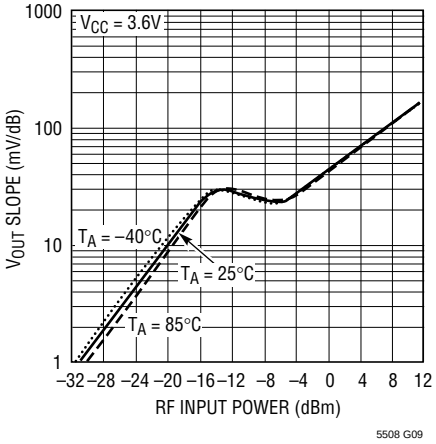


Typical Detector Characteristics, 7000MHz

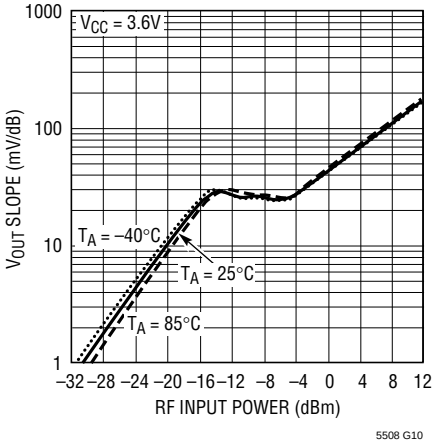


TYPICAL PERFORMANCE CHARACTERISTICS

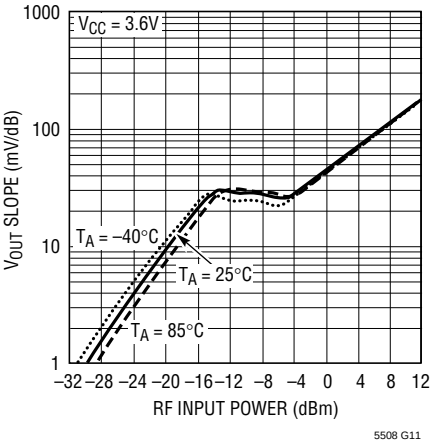
V_{OUT} Slope vs RF Input Power at 300MHz



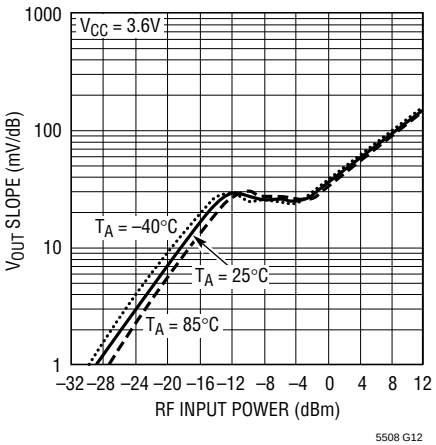
V_{OUT} Slope vs RF Input Power at 1000MHz



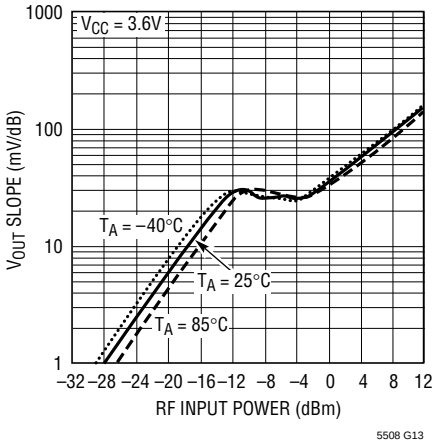
V_{OUT} Slope vs RF Input Power at 2000MHz



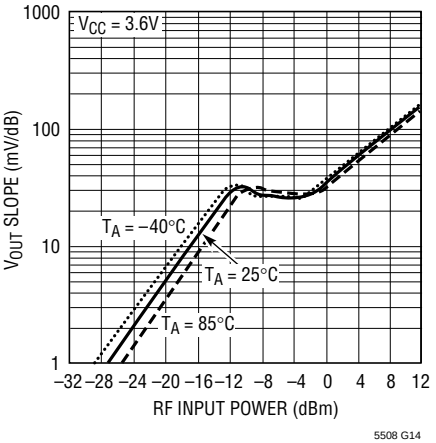
V_{OUT} Slope vs RF Input Power at 3000MHz



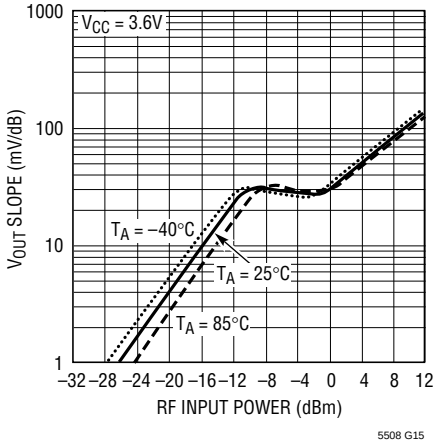
V_{OUT} Slope vs RF Input Power at 4000MHz



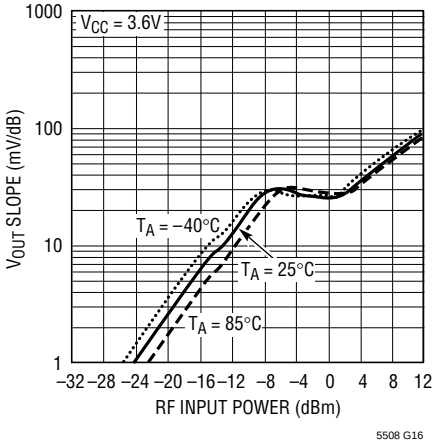
V_{OUT} Slope vs RF Input Power at 5000MHz



V_{OUT} Slope vs RF Input Power at 6000MHz



V_{OUT} Slope vs RF Input Power at 7000MHz

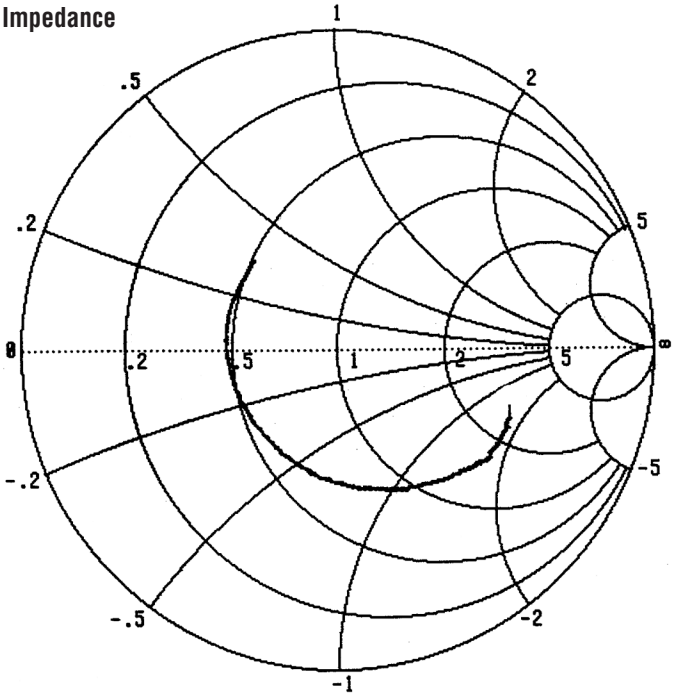


TYPICAL PERFORMANCE CHARACTERISTICS

RF_{IN} Input Impedance (Pin = 0dBm, V_{CC} = 3.6V, T_A = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	129.136	–86.960
1.375	100.771	–92.142
1.750	73.844	–81.141
2.125	60.159	–68.796
2.500	50.135	–58.139
2.875	43.042	–48.927
3.250	37.570	–41.033
3.625	33.924	–33.346
4.000	30.923	–26.405
4.375	28.793	–20.012
4.750	26.992	–14.080
5.125	25.717	–8.323
5.500	24.920	–3.228
5.875	24.318	2.177
6.250	24.549	7.535
6.625	25.273	12.197
7.000	26.337	16.503

S11 Forward Reflection Impedance



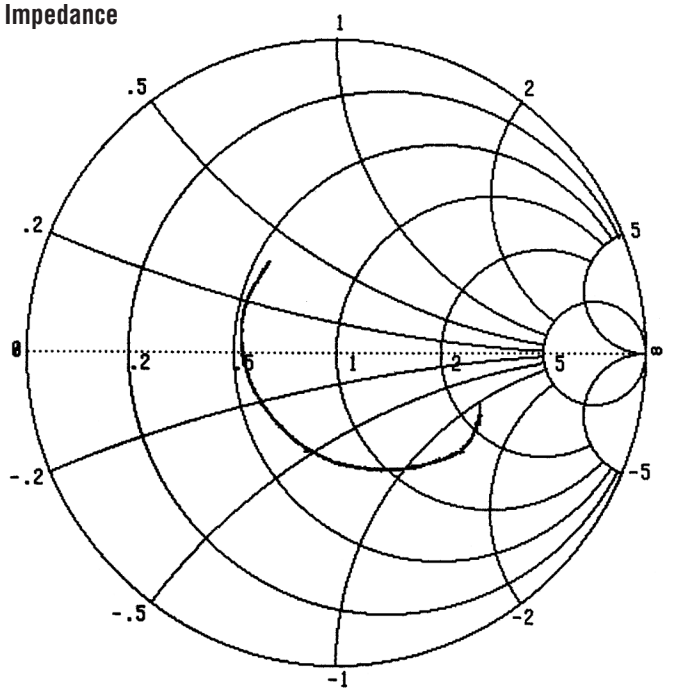
1.000GHz-7.000GHz

5508 TA03

RF_{IN} Input Impedance (Pin = –25dBm, V_{CC} = 3.6V, T_A = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	114.531	–63.267
1.375	95.061	–71.669
1.750	71.491	–64.607
2.125	59.563	–54.798
2.500	51.714	–46.844
2.875	44.940	–39.753
3.250	39.708	–32.738
3.625	36.151	–26.385
4.000	33.227	–20.478
4.375	31.108	–15.107
4.750	29.514	–9.941
5.125	27.899	–4.793
5.500	27.047	0.266
5.875	26.627	5.250
6.250	26.760	10.267
6.625	27.619	14.616
7.000	28.241	18.523

S11 Forward Reflection Impedance



1.000GHz-7.000GHz

5508 TA04

PIN FUNCTIONS

$\overline{\text{SHDN}}$ (Pin 1): Shutdown Input. A logic low on the $\overline{\text{SHDN}}$ pin places the part in shutdown mode. A logic high enables the part. $\overline{\text{SHDN}}$ has an internal 150k pull down resistor to ensure that the part is in shutdown when no input is applied.

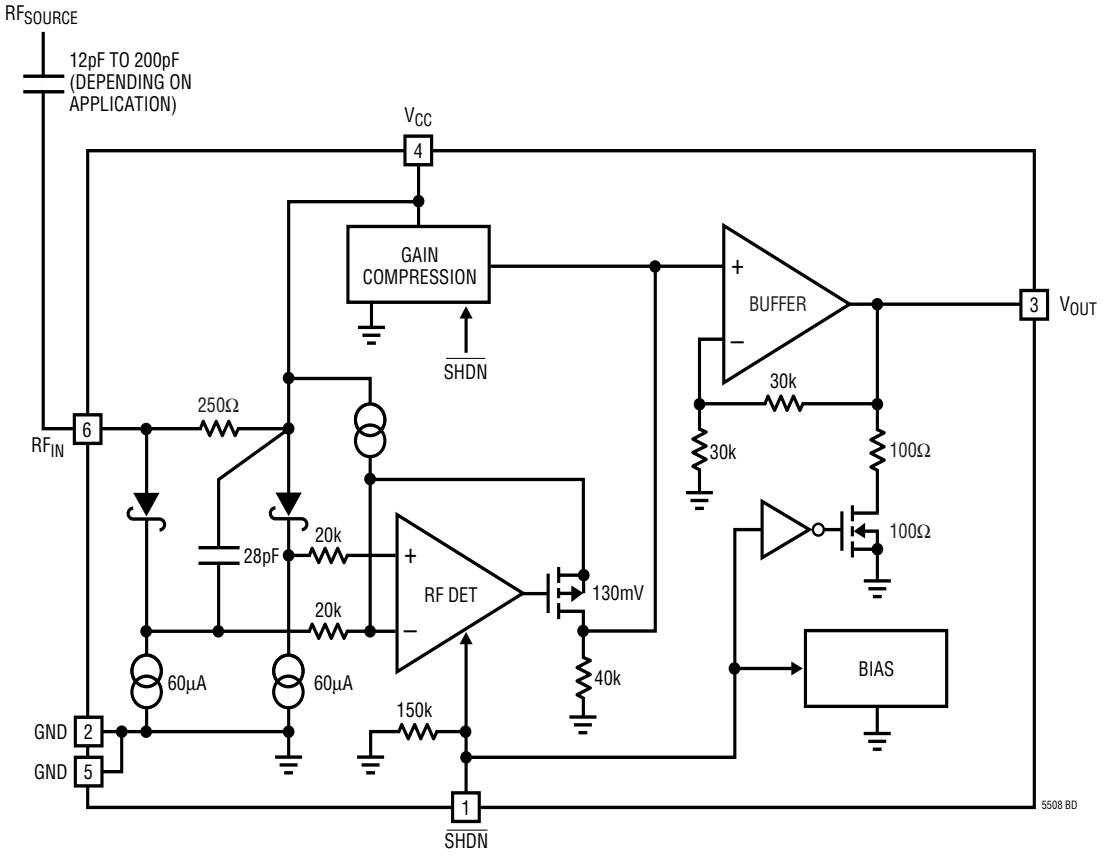
GND (Pin 2, 5): Ground.

V_{OUT} (Pin 3): Detector Output.

V_{CC} (Pin 4): Power Supply Voltage, 2.7V to 6V. V_{CC} should be bypassed appropriately with ceramic capacitors.

RF_{IN} (Pin 6): RF Input Voltage. Referenced to V_{CC}. A coupling capacitor must be used to connect to the RF signal source. The frequency range is 300MHz to 7GHz. This pin has an internal 250Ω termination, an internal Schottky diode detector and a peak detector capacitor.

BLOCK DIAGRAM



APPLICATIONS INFORMATION

Operation

The LTC5508 RF detector integrates several functions to provide RF power detection over frequencies ranging from 300MHz to 7GHz. These functions include an internally compensated buffer amplifier, an RF Schottky diode peak detector and level shift amplifier to convert the RF input signal to DC, a delay circuit to avoid voltage transients at V_{OUT} when coming out of shutdown and a gain compression circuit to extend the detector dynamic range.

Buffer Amplifier

The buffer amplifier has a gain of two and is capable of driving a 2mA load. The buffer amplifier typically has an output voltage range of 0.25V to 1.75V.

RF Detector

The internal RF Schottky diode peak detector and level shift amplifier converts the RF input signal to a low frequency signal. The detector demonstrates excellent efficiency and linearity over a wide range of input power. The Schottky detector is biased at about 60µA and drives a peak detector capacitor of 28pF.

Gain Compression

The gain compression circuit changes the feedback ratio as the RF peak-detected input voltage increases above 60mV. Below 60mV, the voltage gain from the peak detector to the buffer output is 4. Above 120mV, the voltage gain is reduced to 0.85. The compression expands the low power detector range due to higher gain.

Modes of Operation

MODE	$\overline{SHDN}$	OPERATION
Shutdown	Low	Disabled
Enable	High	Power Detect

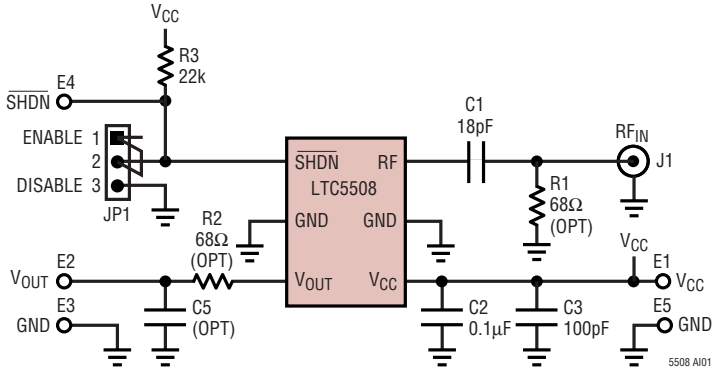
Applications

The LTC5508 can be used as a self-standing signal strength measuring receiver for a wide range of input signals from –32dBm to 12dBm for frequencies from 300MHz to 7GHz.

The LTC5508 can be used as a demodulator for AM and ASK modulated signals with data rates up to 2MHz. Depending on specific application needs, the RSSI output can be split into two branches, providing AC-coupled data (or audio) output and DC-coupled, RSSI output for signal strength measurements and AGC.

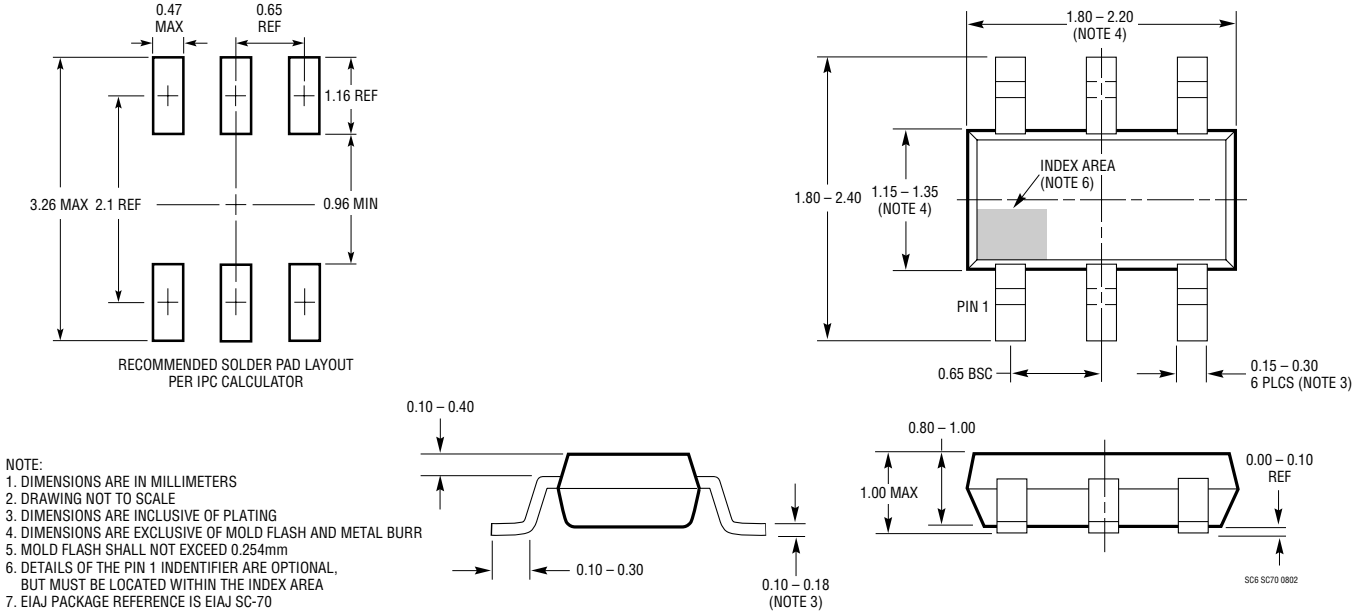
The LTC5508 can be used for RF power detection and control. Refer to Application Note 91, "Low Cost Coupling Methods for RF Power Detectors Replace Directional Couplers."

Demo Board Schematic



PACKAGE DESCRIPTION

SC6 Package
6-Lead Plastic SC70
(Reference LTC DWG # 05-08-1638)



NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
2. DRAWING NOT TO SCALE
3. DIMENSIONS ARE INCLUSIVE OF PLATING
4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
5. MOLD FLASH SHALL NOT EXCEED 0.254mm
6. DETAILS OF THE PIN 1 INDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE INDEX AREA
7. EIAJ PACKAGE REFERENCE IS EIAJ SC-70

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
RF Power Controllers		
LTC1757A	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC1758	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC1957	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC4400	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW
LTC4401	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW
LT5500	1.8GHz to 2.7GHz RF Front End	Dual LNA gain Setting +13.5dB/–14dB at 2.5GHz, Double-Balanced Mixer, $1.8V \le V_{SUPPLY} \le 5.25V$
LT5502	400MHz Quadrature Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply
LTC5505	300MHz to 3.5GHz RF Power Detector	>40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, –4dB to 57dB Linear Power Gain
LTC5507	100kHz to 1GHz RF Power Detector	48dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LT5511	High Signal Level Up Converting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	High Signal Level Down Converting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer

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